# MAINTENANCE MANUAL

### 138-174 MHz POWER AMPLIFIER BOARD 19D423319GI, G2

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### DESCRIPTION

The PA Assembly for MASTR® EXECUTIVE II uses three RF power transistors to provide a pcwer output of 35 Watts. The output power is adjustable using power control potentiometer R11 over a range of 10 to 35 Watts. A single transistor is used in the power control circuit.

Supply voltage for the PA is connected through power leads from the system-audio-squelch board (SAS) to feedthrough capacitors C297 and C298 on the side of the PA assembly. C297, C298, C299, L295 and L296 prevent RF from getting on the power leads. Diode CR295 will cause the main fuse in the fuse assembly to blow if the polarity of the power leads is reversed, providing reverse voltage protection for the radio.

The PA assembly is insulated from vehicle ground to permit operation in positive or negative ground vehicles.

#### - NOTE -

In positive ground vehicles, A- is "hot" with respect to vehicle ground. Shorting the transmitter PA printed wiring board ground pattern to the radio case may cause one of the inline fuses to blow.

The hinged PA heat sink pivots  $90^{\circ}$  to provide access to the power amplifier board, low pass filter and central metering jack J205.

Centralized metering jack J205 is provided for use with GE Test Set Model 4EX3A11 or Test Kit 4EX8K12. The Test Set meters the Ampl-1 drive (exciter output), Ampl-1 Driver and PA current.

#### CIRCUIT ANALYSIS

#### RF AMPLIFIERS

The exciter output is coupled through an RF cable to PA input jack J201. The RF is coupled through a matching network to the base of Class C amplifier Q201. The network matches the 50-ohm input to the base of Q201, and consists of T1, C5, C6 and L2. L1, R3 and C4 comprise a stabilizing network in the base circuit of Q201.

Part of the RF input is rectified by CR1 and applied to voltage divider R1 and R2. This voltage is used to meter the AMPL-1 drive at J205.

Collector voltage to Q201 (Ampl-1) is controlled by power control transistor Q204 and is applied through collector stabilizing network (L3 and R4) and collector feed network T2 and C9. The collector voltage of Q201 is metered through R7 at J205.

The output of Q201 is coupled to the base of Class C driver Q202 through a matching network consisting of C7, T2, C8, T3, C14 and C15. Collector voltage to Q202 is applied through collector stabilizing network Z1 and collector feed network L4 and C16.

Collector current for Q202 is metered across tapped manganin resistor R9 at J205 (Driver Current). The reading is taken on the one-Volt scale with the High Sensitivity button pressed, and read as 10 amperes full scale.

The output of Q202 is applied to the base of Class C Power Amplifier Q203 through C20 and a lowpass filter matching network (L5, C21, C22 and C23). Collector voltage to Q203 is coupled through collector stabilizing network Z2 and collector feed network L6 and C29.



Collector current for Q203 is metered across tapped manganin resistor R10. The reading is taken on the one-Volt scale with the High Sensitivity button pressed, and read as 10 amperes full scale.

Following Q203 is a matching network (L7, C31, T4 and C35) that matches the output of Q203 to the 50-ohm microstrip impedance (W2) to the input of low pass filter. C30 acts as a DC blocking capacitor.

The PA output is coupled through the low-pass filter to the antenna through antenna transfer relay K1901.

Capacitors C36 through C45 provide ground isolation for positive and negative ground operation. C34 provides DC isolation between the transmitter and the antenna.

- WARNING -

The RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

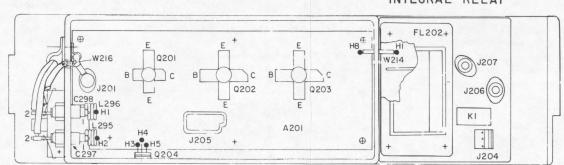
#### POWER CONTROL CIRCUIT

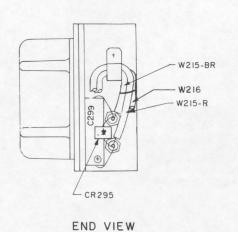
The power control circuit consists of R11 and Q204. R11 controls the base voltage and conduction of Q204. Q204 is connected in series with the collector feed network for Q201, thereby controlling the drive to driver Q202 and the output power. R11 is adjusted to provide the desired output power.

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### PA ASSEMBLY



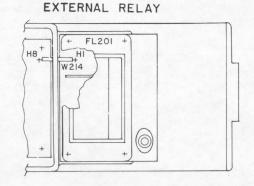


(19C327098, Rev. 6)

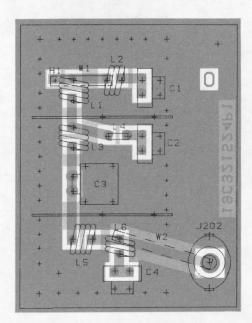
## **OUTLINE DIAGRAM**

138—174 MHz, 35 WATT POWER AMPLIFIER



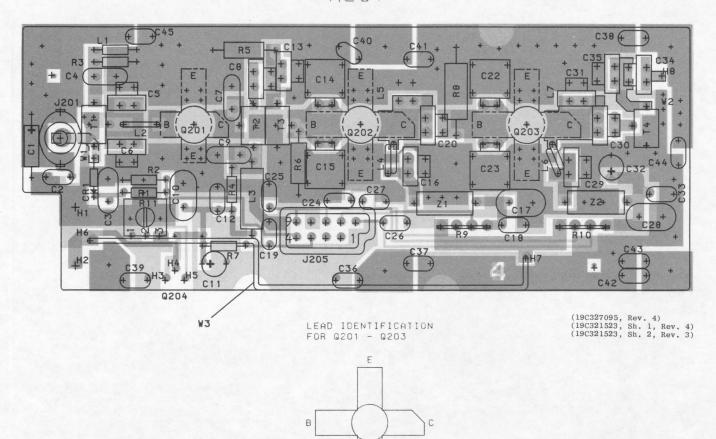


LOW PASS FILTER FL201 (EXTERNAL RELAY)



(19B227367, Rev. 0) (19B226795, Sh. 2, Rev. 0) (19B226795, Sh. 3, Rev. 0)

## COMPONENT BOARD A201



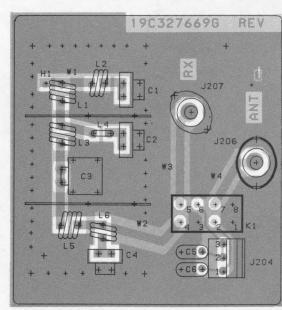
VIEW FROM CASE END

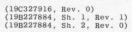
- RUNS ON SOLDER SIDE

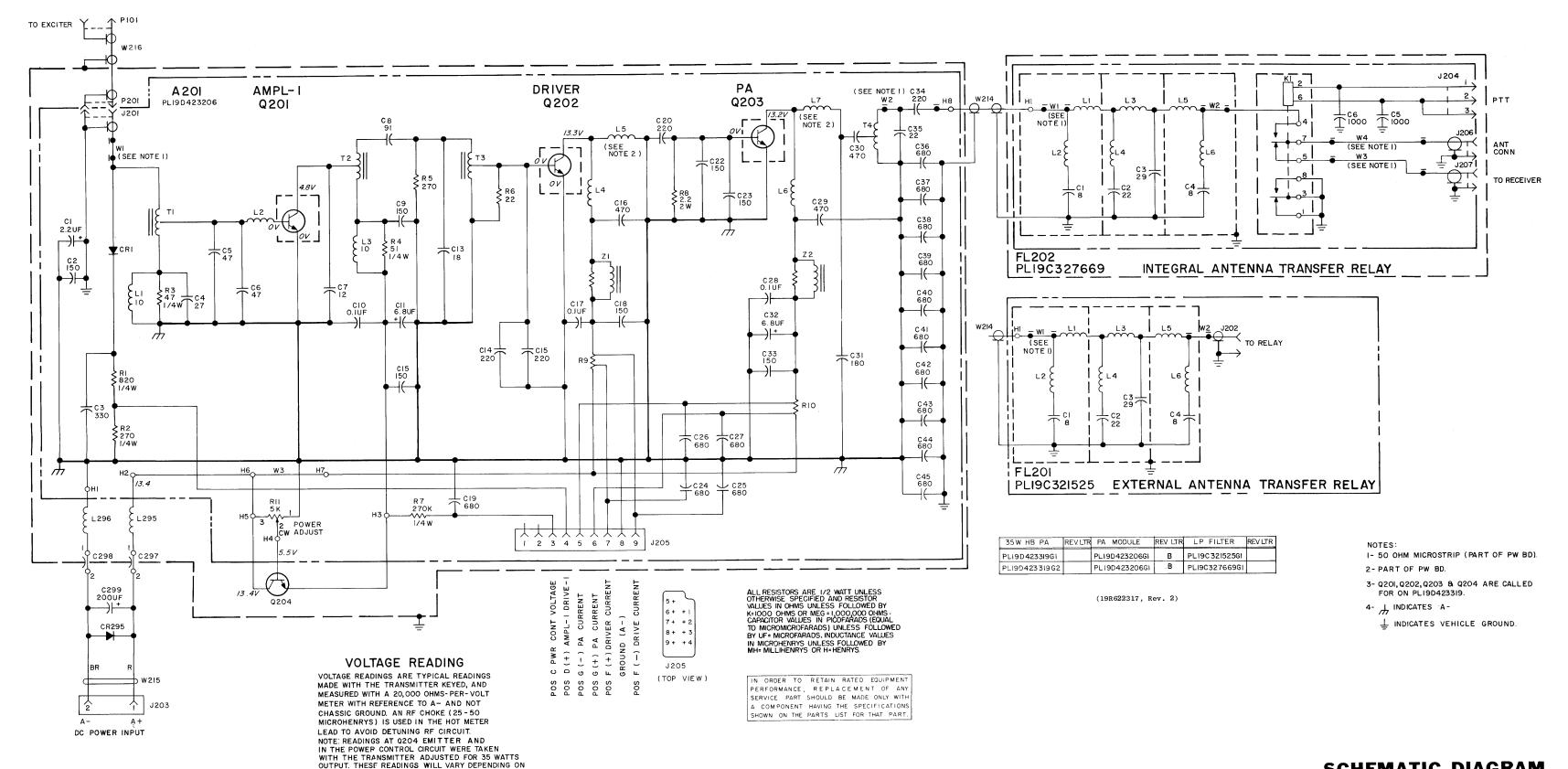
- RUNS ON COMPONENT SIDE

RUNS ON BOTH SIDES

LOW PASS FILTER FL202 (INTEGRAL RELAY)







THE SETTING OF POWER ADJUST CONTROL RII.

### **SCHEMATIC DIAGRAM**

138—174 MHz, 35 WATT POWER AMPLIFIER

Issue 5

### LBI30054

#### PARTS LIST

LB130066D

138-174 MHz POWER AMPLIFIER 19D423319G1, G2

GE PART NO.	DESCRIPTION	
	P.A. BOARD 19D423206G1	
5496267P13	Tantalum: 2.2 µf ±20%, 20 VDCW; sim to Sprague Type 150D.	
19A116655P8	Ceramic disc: 150 pf $\pm 10\%$ , 1000 VDCW; sim to RMC Type JF Discap.	
7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electromotive Type DM-15.	
19A116656P27J0	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef 0 PPM.	
	Earlier than REV A:	
7489162P19	Silver mica: 47 pf $\pm 5\%$ , 500 VDCW; sim to Electro Motive Type DM-15.	
19A700015P21	Metallized teflon: 47 pf ±5%, 250 VDCW.	
19A700105P8	Mica: 12 pf ±5%, 500 VDCW.	
19A700015P28	Metallized teflon: 91 pf ±5%, 250 VDCW.	
19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	
	In REV A & earlier:	
19A700105P28	Mica: 56 pf ±5%, 500 VDCW.	
19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.	
	Tantalum: 6.8 μf ±20%, 35 VDCW.	
19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	
19A700015P10	Metallized teflon: 18 pf ±5%, 250 VDCW.	
19A116795P220J	Silver mica: 220 pf $\pm 5\%$ , 250 VDCW; sim to Underwood Type J1HF.	
19A116679P470K	Mica: 470 pf ±10%, 250 VDCW.	
19A116080P107	Polyester: 0.1 \( \text{pf} \) \( \pm \) \( \text{to VDCW} \).	
19A116655P8	Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	
19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	
19A116679P220K	Mica: 220 pf ±10%, 250 VDCW.	
10.11	In REV A & earlier:	
	Mica: 470 pf ±10%, 250 VDCW.	
	Mica: 56 pf ±5%, 250 VDCW. Deleted by REV B.  Silver mica: 150 pf ±5%, 250 VDCW; sim to	
10VIIO (2011909	Underwood Type J1HF.  Earlier than REV A:	
19A116795P220J	Silver mica: 220 pf ±5%, 250 VDCW; sim to Underwood Type J1HF.	
19A116655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	
19A116080P107	Polyester: 0.1 µf ±10%, 50 VDCW.	
19A116679P470K	Mica: 470 pf ±10%, 250 VDCW.	
	Wetsiliand tofices 190 of the SEC VICON	
19A700015P35	Metallized teflon: 180 pf ±5%, 250 VDCW.	
	5496267P13 19A116655P8 7489162P39 19A116656P27J0 7489162P19 19A700015P21 19A700015P28 19A700015P28 19A116655P8 19A700105P28 19A116655P8 19A700015P10 19A134202P15 19A116655P8 19A700015P10 19A116795P220J 19A116655P8 19A116655P8 19A116655P8 19A116655P8 19A116655P8 19A116655P8 19A116655P8 19A116655P18 19A116679P220K	

SYMBOL	GE PART NO.	D. DESCRIPTION	
C33	19All6655P8	Ceramic disc: 150 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	
C34	19A700015P37	Metallized teflon: 220 pf ±5%, 250 VDCW.	
C35	19A700015P12	Metallized teflon: 22 pf ±5%, 250 VDCW.	
C36	19All6655P18	Ceramic disc: 680 pf ±10%, 1000 VDCW; sim to	
thru C45		RMC Type JF Discap.	
CR1	19A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.	
		JACKS AND RECEPTACLES	
J201	19A130924G1	Connector: jack type; sim to Cinch 14H11613.	
J205	19B219374G1	Connector: 9 contacts.	
L1	19A700024P25	Coi1, RF: 10.0 μh ±10%, 3.70 ohms DC res max.	
L2	19A130609G1	Coil.	
L3	19A700000P123	Coil, RF: 10.0 µh ±10%, 0.26 ohms DC res max.	
L4*	19A136531P1	Coil.	
		In REV A & earlier:	
	19A129561P1	Coil.	
L5		(Part of printed board 19D423205P1).	
L6	19A12956lPl	Coil.	
L7		(Part of printed board 19D423205P1).	
		neg ramona	
		RESISTORS	
R1	19A700106P61	Composition: 820 ohms ±5%, 1/4 w.	
R2	19A700106P49	Composition: 270 ohms ±5%, 1/4 w.	
R3	19A700106P31	Composition: 47 ohms ±5%, 1/4 w.	
R4	19A700106P32	Composition: 51 ohms ±5%, 1/4 w.	
R5	19A700113P39	Composition: 100 ohms ±5%, 1/2 w.	
R6	19A700113P23	Composition: 22 ohms ±5%, 1/2 w.	
R7	3R152P274J	Composition: 270K ohms ±5%, 1/4 w.	
R8	19A700050P17	Wirewound: 2.2 ohms ±10%, 2 w.	
R9 and	19C320212P2	Shunt resistor.	
R10 R11	19Al16559P102	Variable, cermet: 5K ohms ±20%, 0.5 w; sim to CTS Series 360.	
		TO AND DODUCES	
m.1	10410053455		
T1 thru T3	19A129564G1	Transformer.	
T4	19A129574G1	Transformer.	
W1 and W2		(Part of printed board 19D423205P1).	
₩3	19B226909G1	Jumper.	
		NETWORKS	
Z1		FILTER ASSEMBLY 19B219649G1	
and Z2			
L1	19A129346G2	Coil.	
		neg remond	
R1	3R78P100K	Composition: 10 ohms ±10%, 1 w.	
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SYMBOL	GE PART NO. DESCRIPTION	
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C297 and C298	19A116708P1	Ceramic, feed-thru: 0.01 $\mu f$ +100%-0%, 500 VDCW; sim to Erie Style 327.
C299	19A115680P10	Electrolytic: 200 µf +150% -10%, 18 YDCW; sim to Mallory Type TTX.
		DIODES AND RECTIFIERS
CR295	19A116783P1	Rectifier, silicon: 100 VDC blocking, 6 amps.
WY 0.03		LOW PASS FILTER
FL201		(EXTERNAL RELAY) 19C321525G1
C1	19A116679P8D	Metallized teflon: 8 pf ±.5 pf, 250 VDCW.
C2 C3	19A700015P12 19A116795P29J	Metallized teflon: 22 pf ±5%, 250 VDCW.  Silver mica: 29 pf ±5%, 250 VDCW; sim to
		Underwood Type JlHF.
C4	19A116679P8D	Metallized teflon: 8 pf ±.5 pf, 250 VDCW.
		JACKS AND RECEPTACLES
J202	19A130924G1	Connector: jack type; sim to Cinch 14H11613.
Ll	19A129569P1	Coil.
L2 L3	19A129570P1 19A129569P1	Coil.
L3 L4	19A129575P1	Coil.
L5	19A129569P1	Coil.
rė	19A129570P1	Coil.
		CABLES
W1 and W2		(Part of printed board 19C321524P1).
FL202		LOW PASS FILTER (INTEGRAL RELAY) 19C327669G1
Cl	19A116679P8D	Metallized teflon: 8 pf ±.5 pf, 250 VDCW.
C2	19A700015P12	Metallized teflon: 22 pf ±5%, 250 VDCW.
C3	19A116795P29J	Silver mica: 29 pf ±5%, 250 VDCW; sim to Underwood Type J1HF.
C4	19A116679P8D	Metallized teflon: 8 pf ±.5 pf, 250 VDCW.
C5 and C6	19A116655P20	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
J204	19A116659P55	JACKS AND RECEPTACLES Connector, printed wiring: 3 contacts; sim to
1204	19A130924G1	Molex 09-65-1031.  Connector, receptacle: jack type; sim to Cinch
J206 and J207	10413052401	14H11613.
К1	19A700061P1	Hermetic sealed: 180-341 ohms coil res, 8-16.3 VDC; sim to GE 3SAV1760A2, CP Clare HFW-1201558, or Potter-Brumfield HCM6160.
L1	19A129569P1	Coil.
L2	19A129570P1	Coil.
	19A129569P1	Coil.
L3	10.112000011	

SYMBOL	GE PART NO.	DESCRIPTION	
L4	19A129575Pl	Coil.	
L5	19A129569P1	Coil.	
L6	19A129570P1	Coil.	
Wl thru W4		(Part of printed board 19C327670Pl).	
L295 and L296	19A130608G1	Coil.	
Q201	19A134060P1	Silicon, NPN.	
Q202	19A134060P2	Silicon, NPN.	
Q203	19A134060P3	Silicon, NPN.	
Q204	19A116742P1	Silicon, NPN.	
W214	19A130607G1	Cable, RF: approx 1 foot long.	
W215	19B227058G1	Cable: approx 1 foot long.	
W216	19A130909G1	Cable, RF: approx 7-1/2 inches long.	
		MISCELLANEOUS	
	19C321591G2	Heat sink. (Used with Q201-Q203).	
	19C321595P1	Insulator. (Used with Q201-Q203).	
	5492178P2	Washer, spring tension; sim to Wallace Barnes 375-20. (Used with Q201-Q203).	
	N207P15C6	Nut, hex: No. 8-32. (Used with Q201-Q203).	
	19A134016P1	Insulator, bushing. (Used with Q204).	
	19A116023P1	Insulator, plate. (Used with Q204).	
	19D416275P3	Filter housing. (FL201).	
	19B201074P312	Tap screw, Phillips POZIDRIV®: No. 6-32 x 3/4. (Secures FL201 can).	
	19B201074P305	Tap screw, Phillips POZIDRIV®: No. 6-32 x 5/16. (Secures A201 board).	
	19A129434P1	Washer. (Used with L295, L296).	
	4029851P6	Clip loop: sim to Weckesser Co. 5/16-4-128. (Used with w215).	
	19B226952G1	P.A. cover.	

### **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A <u>Power Amplifier Board 19D423206G1</u>
  To improve operation. Changed C4.
- REV. B Power Amplifier Board 19D423206G1

  To increase output in 174 MHz (high end) range. Changed C9, C20, C22, C23 and L4. Deleted C21.